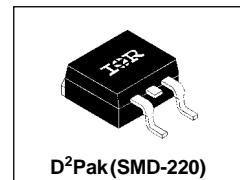


32CTQ030S

SCHOTTKY RECTIFIER

30 Amp



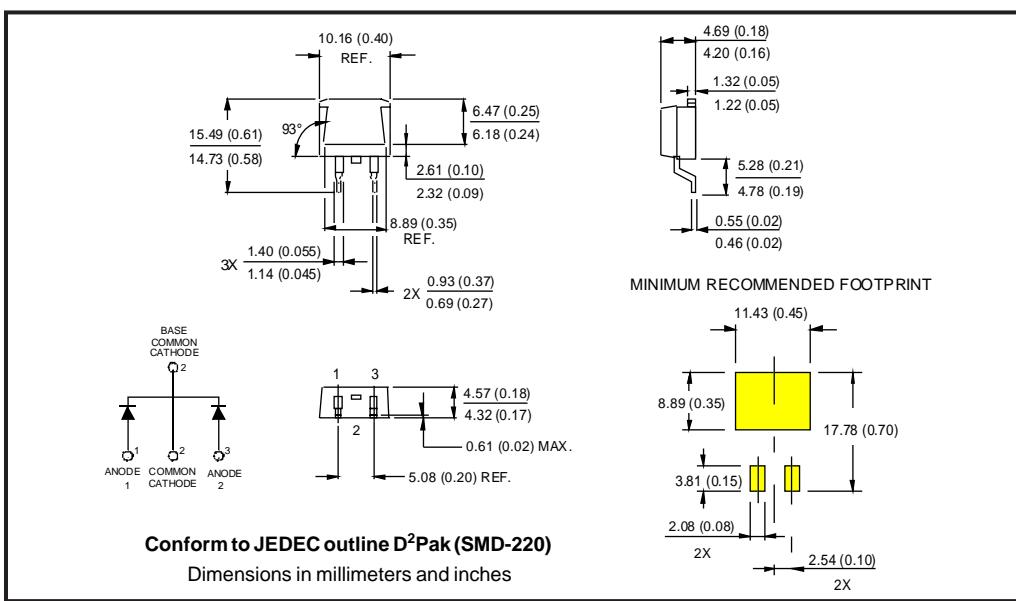
Major Ratings and Characteristics

Characteristics	32CTQ030S	Units
I _{F(AV)} Rectangular waveform	30	A
V _{RRM}	30	V
I _{FSM} @ tp=5μs sine	900	A
V _F @ 15Apk, T _J =125°C (perleg)	0.40	V
T _J	-55 to 150	°C

Description/Features

The 32CTQ030S center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150°C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 150°C T_J operation
- Center tap D²Pak package
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



32CTQ030S

PD-20570 09/98

International
 Rectifier

Voltage Ratings

Part number	32CTQ030S		
V_R Max. DC Reverse Voltage (V)			30
V_{RWM} Max. Working Peak Reverse Voltage (V)			

Absolute Maximum Ratings

Parameters	32CTQ...S	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current (Per Leg) * See Fig. 5 (Per Device)	15	A	50% duty cycle @ $T_C = 115^\circ C$, rectangular waveform
	30		
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current (Per Leg) * See Fig. 7	900	A	5μs Sine or 3μs Rect. pulse Following any rated load condition and with 10ms Sine or 6ms Rect. pulse applied
	250		
E_{AS} Non-Repetitive Avalanche Energy (Per Leg)	13	mJ	$T_J = 25^\circ C$, $I_{AS} = 3$ Amps, $L = 2.90$ mH
I_{AR} Repetitive Avalanche Current (Per Leg)	3	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	32CTQ...S	Units	Conditions
V_{FM} Max. Forward Voltage Drop (Per Leg) * See Fig. 1 (1)	0.49	V	$T_J = 25^\circ C$
	0.58	V	
	0.40	V	
	0.53	V	$T_J = 125^\circ C$
I_{RM} Max. Reverse Leakage Current (Per Leg) * See Fig. 2 (1)	1.75	mA	$T_J = 25^\circ C$ $T_J = 125^\circ C$ $V_R = \text{rated } V_R$
	97	mA	
V_{FTO} Threshold Voltage	0.233	V	$T_J = T_J$ max.
r_t Forward Slope Resistance	9.09	$\text{m}\Omega$	
C_T Max. Junction Capacitance (Per Leg)	1300	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) $25^\circ C$
L_S Typical Series Inductance (Per Leg)	8.0	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change (Rated V_R)	10,000	V/ μs	

(1) Pulse Width < 300μs, Duty Cycle <2%

Thermal-Mechanical Specifications

Parameters	32CTQ...S	Units	Conditions
T_J Max. Junction Temperature Range	-55 to 150	°C	
T_{stg} Max. Storage Temperature Range	-55 to 150	°C	
R_{thJC} Max. Thermal Resistance Junction to Case (Per Leg)	3.25	°C/W	DC operation * See Fig. 4
wt Approximate Weight	2(0.07)	g(oz.)	
Case Style	D ² Pak		JEDEC

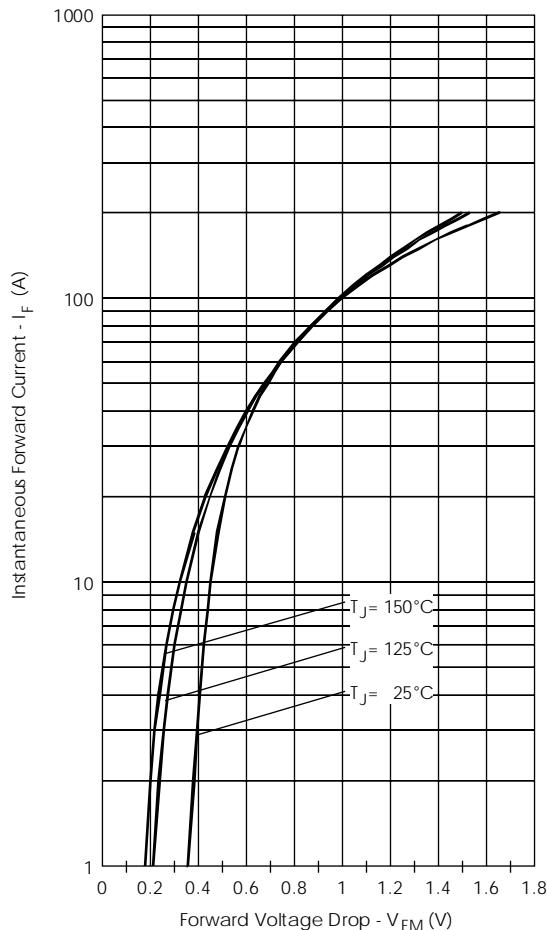


Fig.1-Max. Forward Voltage Drop Characteristics
 (PerLeg)

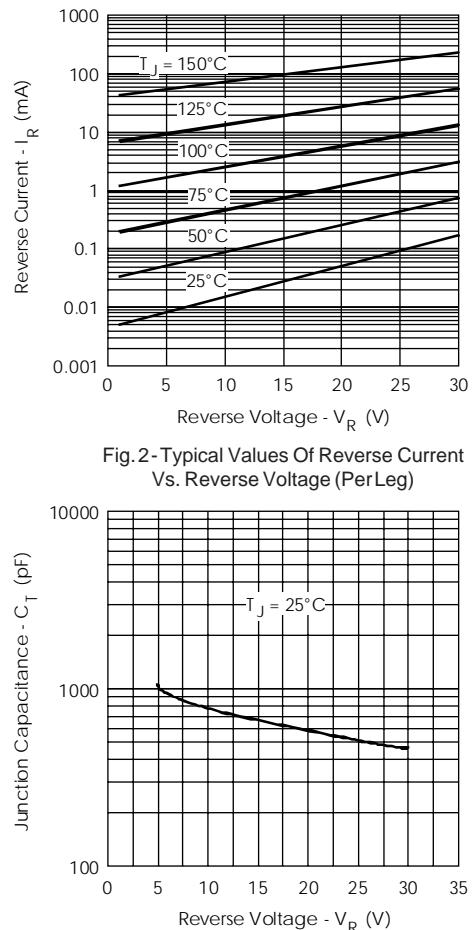


Fig.2-Typical Values Of Reverse Current
 Vs. Reverse Voltage (PerLeg)

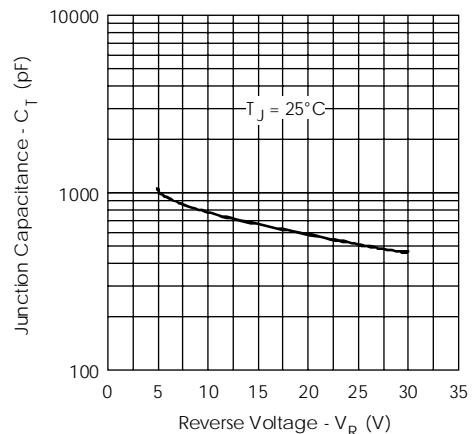


Fig.3-Typical Junction Capacitance
 Vs. Reverse Voltage (PerLeg)

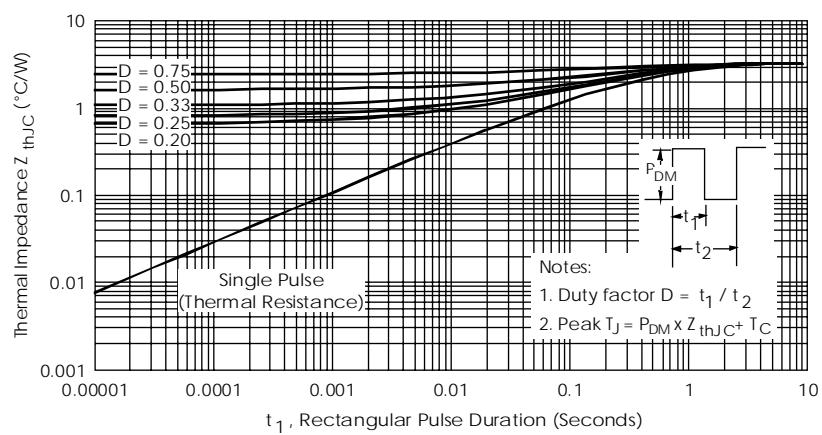


Fig.4-Max. Thermal Impedance Z_{thJC} Characteristics (PerLeg)

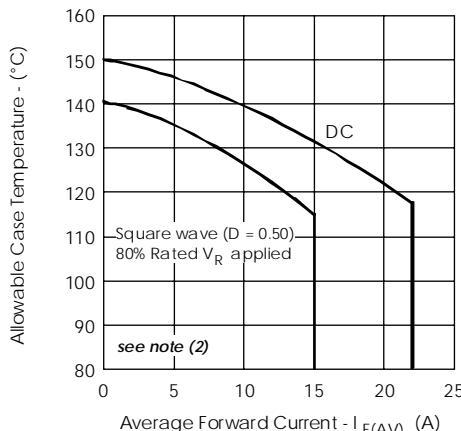


Fig.5-Max. Allowable Case Temperature Vs. Average Forward Current (PerLeg)

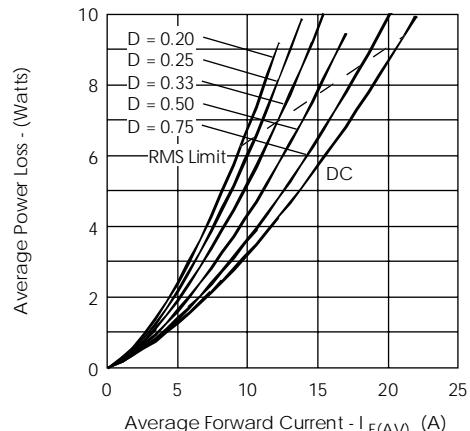


Fig.6-Forward Power Loss Characteristics (PerLeg)

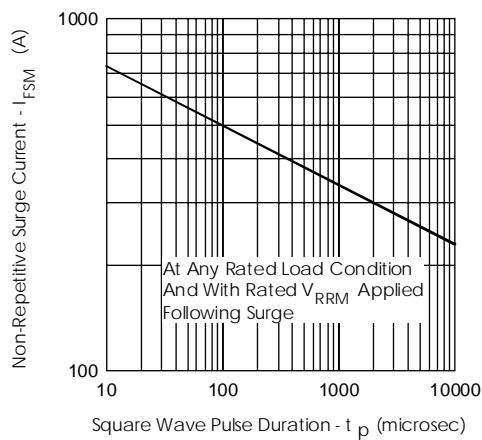


Fig.7-Max. Non-Repetitive Surge Current (PerLeg)

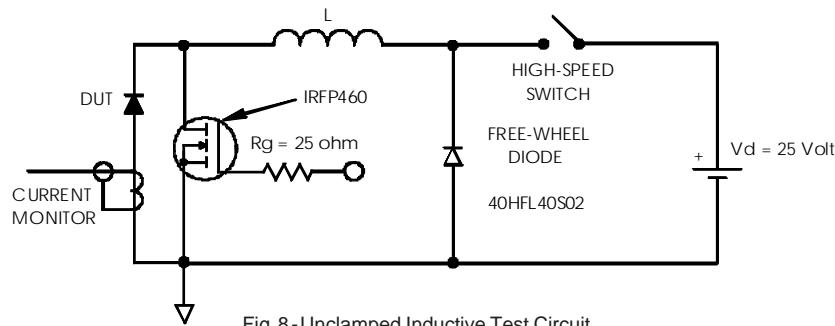


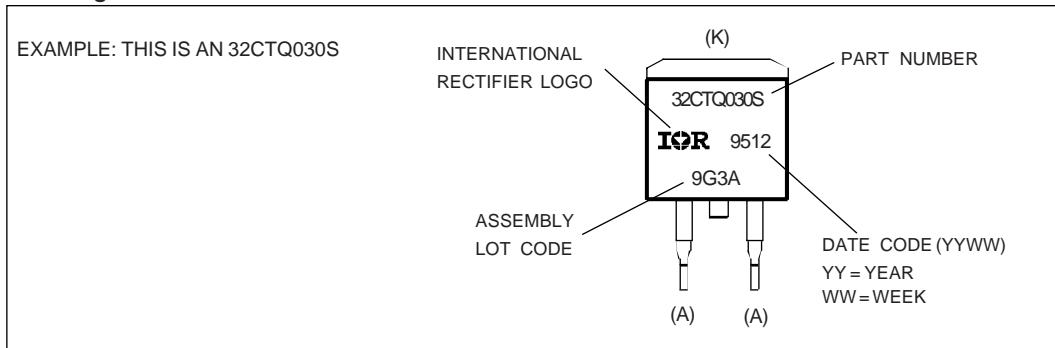
Fig.8-Unclamped Inductive Test Circuit

(2) Formula used: $T_c = T_j - (P_d + P_{d,REV}) \times R_{thJC}$;

$P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

$P_{d,REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\% \text{ rated } V_R$

Marking Information



Tape & Reel Information

